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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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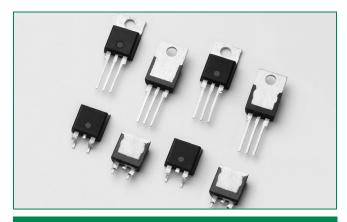






SJxx25xx Series

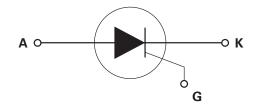




Description

This SJxx25xx high temperature SCR series is ideal for uni-directional switch applications such as phase control in heating, motor speed controls, converters/rectifiers and inrush current controllers. These SCRs have a low gate current trigger level of 6mA,10mA or 35mA maximum at approximately 1.5V

Schematic Symbol



Main Features

Symbol	Value	Unit
I _{T(RMS)}	25	А
V _{DRM} /V _{RRM}	400 or 600	V
I _{GT}	6 to 35	mA

Features & Benefits

- Halogen free and RoHS compliant
- 150°C maximum junction temperature
- Surge capability up to 350 A at 60 Hz half cycle

Applications

Typical applications include AC Generator (ACG) rectifiers, battery voltage regulators, generic converters, inrush current controller in various AC to DC applications and soft starter for low power AC motor. Additional applications include controls for power tools, home/brown good and white goods appliances.

Internally constructed isolated packages are offered for ease of heat sinking with high isolation voltage.

Absolute Maximum Ratings

Symbol	Parameter	Test Conditions		Value	Unit
V_{DRM}/V_{RSM}	Peak non-repetitive blocking voltage	Pw=1	00 μs	$V_{DRM}/V_{RRM}+100$	V
		SJxx25Lx	T _C = 100°C		
I _{T(RMS)}	RMS on-state current	SJxx25Rx	T _C = 125°C	25	А
		SJxx25Nx	1 _C = 125 C		
		SJxx25Lx	$T_{\rm C} = 100^{\circ}{\rm C}$		
I _{T(AV)}	Average on-state current	SJxx25Rx	T _C = 125°C	16	А
		SJxx25Nx	1 _C = 125 C		
	Peak non-repetitive surge current	single half cycle; f = 50Hz;		300	A
I _{TSM}		T _J (initial) = 25°C			
13101	· -	single half cycle; f = 60Hz; T, (initial) = 25°C		350	
l ² t	l²t Value for fusing	t _p = 8		510	A ² s
-		-			
di/dt	Critical rate of rise of on-state current	f = 60Hz ; T _J = 150°C		125	A/µs
I _{GM}	Peak gate current	T _J = 150°C		3	А
$P_{G(AV)}$	Average gate power dissipation	T _J = 150°C		0.6	W
T _{stg}	Storage temperature range			-40 to 150	°C
T _J	Operating junction temperature range			-40 to 150	°C

Note: xx=voltage/10, x=sensitivity

SJxx25xx Series

25 Amps High Junction Temperature SCRs

Electrical Characteristics (T₁ = 25°C, unless otherwise specified)

Symbol	Test Conditions	Value			Unit	
Syllibol	Symbol lest conditions			SJxx25x1	SJxx25x2	Offic
	V 12V B 60 O	MAX.	35	6	10	A
I _{GT}	$V_D = 12V R_L = 60 \Omega$	MIN.	8	2	5	mA
V _{GT}	$V_D = 12V R_L = 60 \Omega$ MAX.			1.5		V
dv/dt	$V_D = 67\% V_{DRM}$; gate open; $T_J = 125$ °C	MIN.	800	70	500	V/µs
αν/αι	$V_D = 67\% V_{DRM}$; gate open; $T_J = 150$ °C	IVIIIN.	400	-	200	ν/μ5
V_{GD}	$V_D = V_{DRM} R_L = 3.3 \text{ k}\Omega T_J = 125 \text{°C}$	MIN.	0.2		V	
I _H	$I_{T} = 400 \text{mA} \text{ (initial)}$	MAX.	75	15	35	mA
t _q	$I_{_{\rm T}} = 2A; t_{_{\rm p}} = 50 \mu s; dv/dt = 5V/\mu s; di/dt = 30A/\mu s$ MAX			40		μs
t _{gt}	$I_{G} = 2 \times I_{GT}$ PW = 15 μ s $I_{T} = 50$ A	TYP.		2		μs

Note: xx=voltage/10, x=package

Static Characteristics

Symbol		Test Conditions			Unit
V_{TM}	Com	emponent $I_T = 50A$; $t_p = 380 \mu s$ MAX.		1.6	V
		T _J = 25°C		10	
I _{DRM} / I _{RRM}	$V_{DRM} = V_{RRM}$	T _J = 125°C	MAX.	1000	μΑ
	T _J = 150°C		3000		

Thermal Resistances

Symbol	Parameter	Parameter		
R	Junction to case (AC)	SJxx25Rx SJxx25Nx	1.0	°CM
θ(JC)	Canonich to case (N.C)	SJxx25Lx	2.3	G/ V V

Note: xx=voltage/10, x=sensitivity

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

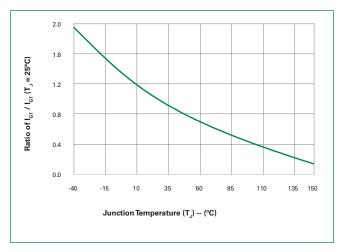


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

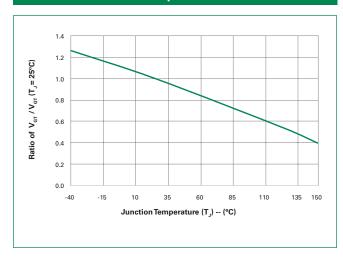




Figure 3: Normalized DC Holding Current vs. Junction Temperature

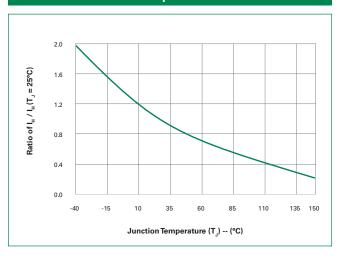


Figure 4: On-State Current vs. On-State Voltage (Typical)

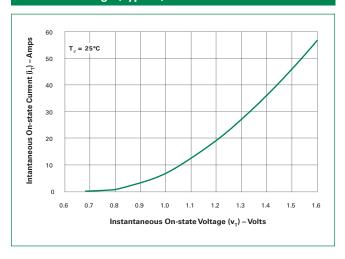


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

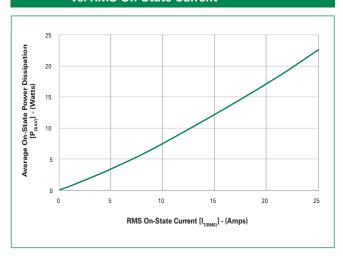


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

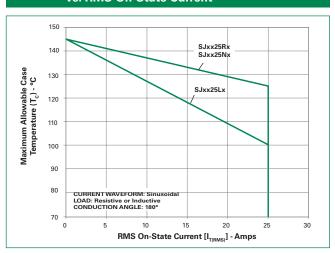


Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

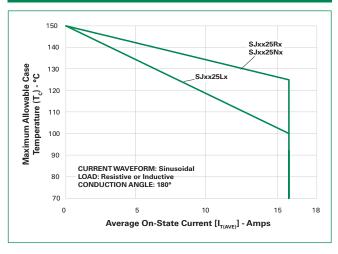


Figure 8: Peak Capacitor Discharge Current

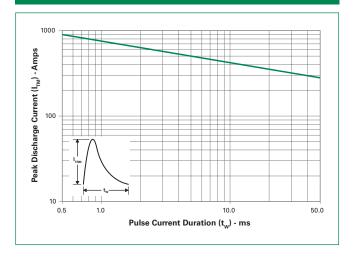


Figure 9: Peak Capacitor Discharge Current Derating

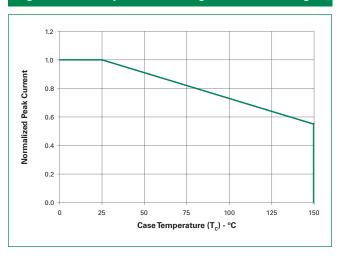
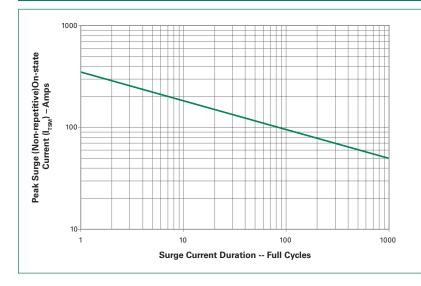


Figure 10: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 60 Hz Sinusoidal

LOAD: Resistive

RMS On-State Current: $[I_{\text{T(RMS)}}]$: Maximum Rated Value at Specified Case Temperature

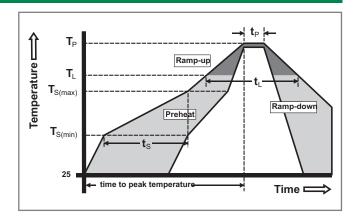
Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.

25 Amps High Junction Temperature SCRs

Soldering Parameters

Reflow Co	ndition	Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ramp up rate (Liquidus Temp) (T _L) to peak		5°C/second max	
T _{S(max)} to T _L	- Ramp-up Rate	5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nenow	-Time (t _L)	60 – 150 seconds	
PeakTemp	erature (T _P)	260 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exc	ceed	280°C	



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized compound meeting flammability rating V-0.
Lead Material	Copper Alloy

Design Considerations

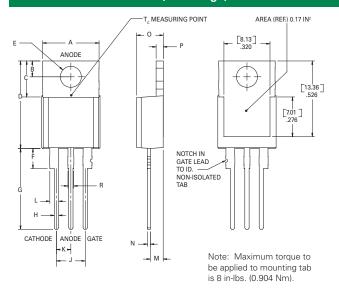
Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -55°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E
Moisture Sensitivity Level	Level 1, JEDEC-J-STD-020D

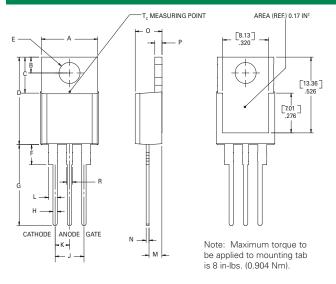
25 Amps High Junction Temperature SCRs

Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



Dimension	Inc	hes	Millin	neters
Dimension	Min	Max	Min	Max
А	0.380	0.420	9.65	10.67
В	0.105	0.115	2.67	2.92
С	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
Е	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
Н	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
М	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
0	0.178	0.188	4.52	4.78
Р	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

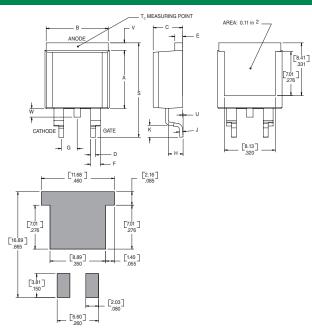
Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Dimension		Inc	hes	Millin	neters
Diffiel	ISIOII	Min	Max	Min	Max
А		0.380	0.420	9.65	10.67
В		0.105	0.115	2.67	2.92
С		0.230	0.250	5.84	6.35
D		0.590	0.620	14.99	15.75
Е		0.142	0.147	3.61	3.73
F		0.110	0.130	2.79	3.30
G		0.540	0.575	13.72	14.61
Н		0.025	0.035	0.64	0.89
J		0.195	0.205	4.95	5.21
K		0.095	0.105	2.41	2.67
L		0.060	0.075	1.52	1.91
N	1	0.085	0.095	2.16	2.41
N		0.018	0.024	0.46	0.61
0		0.178	0.188	4.52	4.78
Р		0.045	0.060	1.14	1.52
R		0.038	0.048	0.97	1.22

25 Amps High Junction Temperature SCRs

Dimensions -TO- 263AB (N-package) - D2-Pak Surface Mount



Dimension	Inches		Millin	neters
Dimension	Min	Max	Min	Max
А	0.360	0.370	9.14	9.40
В	0.380	0.420	9.65	10.67
С	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
Е	0.045	0.060	1.14	1.52
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
Н	0.092	0.102	2.34	2.59
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.88
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.016	1.78

Product Selector

Part Number	Vol	tage	Gate Sensitivity	Туре	Package	
rait ivuilibei	400V	600V	Gate Sensitivity	туре		
SJxx25L	X	X	35mA	Standard SCR	TO-220L	
SJxx25R	X	X	35mA	Standard SCR	TO-220R	
SJxx25N	X	X	35mA	Standard SCR	TO-263	
SJxx25L1	X	X	6mA	Standard SCR	TO-220L	
SJxx25R1	X	X	6mA	Standard SCR	TO-220R	
SJxx25N1	X	X	6mA	Standard SCR	TO-263	
SJxx25L2	X	X	10mA	Standard SCR	TO-220L	
SJxx25R2	Х	Х	10mA	Standard SCR	TO-220R	
SJxx25N2	X	X	10mA	Standard SCR	TO-263	

Note: xx = Voltage/10

Packing Options

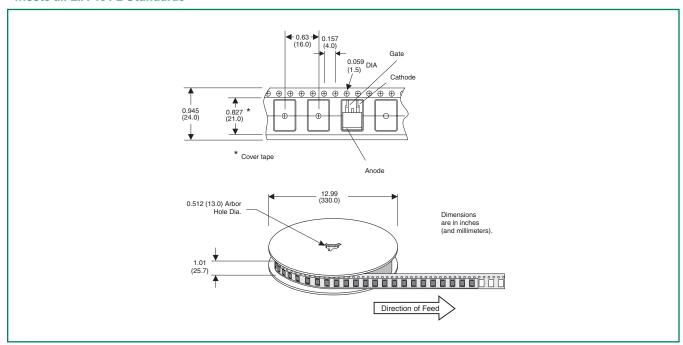
Part Number	Marking	Weight	Packing Mode	Base Quantity
SJxx25LxTP	SJxx25Lx	2.2g	Tube	500 (50 per tube)
SJxx25RxTP	SJxx25Rx	2.2g	Tube	500 (50 per tube)
SJxx25NxTP	SJxx25Nx	1.6g	Tube	500 (50 per tube)
SJxx25NxRP	SJxx25Nx	1.6g	Embossed Carrier	500

Note: xx=voltage/10, x=sensitivity

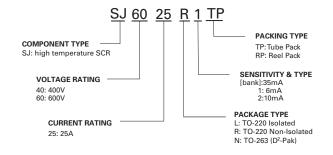


TO-263 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards

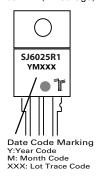


Part Numbering System



Part Marking System

TO-220 AB - (L and R Package) TO-263 AB - (N Package)



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